Electronic Structure of Misfit Layered Compound (LaSe)_{1.14}(NbSe₂)₂ from First-Principles

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Abstract. Transition metal dichalcogenides (TMDs) reveal possess several interesting physical properties including superconductivity with in-plane upper critical magnetic fields much higher than the Pauli limit explained be means of unconventional Ising pairing mechanisms [1]. Misfit layered (LaSe)_{1.14}(NbSe₂)₂ is a stack of TMDC layers intercalated by the LaSe layers. Those systems are superconductors even they are arranged in different vertical stackings [2,3]. We discuss electronic structure from density functional theory calculations for misfit layered (LaSe)_{1.14}(NbSe₂)₂ compound for different bulk stacking and slab configurations, calculate quasiparticle interference in normal state using T-matrix approach [4] by means of tight-binding model [5] fitted to the first-principles calculations relevant for Fourier-transform scanning tunneling spectroscopy.

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